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A First Principle Study of the LaAlO<sub>3</sub>/SrTiO<sub>3</sub> Heterointerface HANGHUI CHEN, Department of Physics, Yale University, SOHRAB ISMAIL-BEIGI, Department of Applied Physics, Yale University — In order to understand the origin of the intriguing high mobility quasi two dimensional electron gas formed at the LaAlO<sub>3</sub>/SrTiO<sub>3</sub>(001) heterointerface, we carry out first principle calculations on the electronic structures and properties of complementary interface. The intrinsic polar properties are investigated and the average electronic potential increase by each LaAlO<sub>3</sub> layer is calculated, which can account for the recent observed experiment fact that the heterointerface is not metallic until the number of LaAlO<sub>3</sub> layers reaches a critical value. We also study the effects of different surface terminations of SrTiO<sub>3</sub> which surprisingly turn out to influence the electronic structure of the interface and so far have not been focused on in experiments.

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